KXE00 Series

Accelerometers

Analog Output

KXE00-1000 — Single Axis X



APPLICATIONS

Motion Detection/Monitoring

Vibration Detection/Monitoring

Vehicle Active Suspension Systems Vehicle Crash Detection Engine Misfire Detection

FEATURES

PROPRIETARY TECHNOLOGY

Lead-free Solderability

High Shock Survivability

Excellent Temperature Performance

Low Noise Density

Low Power Consumption

User Definable Bandwidth

Factory Programmable Offset and Sensitivity

Self-test Function

These high-performance silicon micromachined linear accelerometers and inclinometers consists of a sensor element and an ASIC packaged in a standard 16-pin SOIC wide-body package. The sensor element is fabricated from single-crystal silicon with proprietary Deep Reactive Ion Etching (DRIE) processes, and is protected from the environment by a hermetically-sealed silicon cap wafer at the wafer level.

The KXE00 series is designed to provide a high signal-to-noise ratio with excellent performance over temperature. Sensitivity is factory programmable allowing customization for applications requiring ± 10.0 g to ± 40.0 g ranges. Sensor bandwidth is user-definable.

The sensor element functions on the principle of differential capacitance. Acceleration causes displacement of a silicon structure resulting in a change in capacitance. An ASIC, using a standard CMOS manufacturing process, detects and transforms changes in capacitance into an analog output voltage, which is proportional to acceleration. The sense element design utilizes common mode cancellation to decrease errors from process variation and environmental stress.

Precision in Motion

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KXE00 Series

PRODUCT SPECIFICATIONS

PERFORMANCE SPECIFICATIONS								
PARAMETERS	UNITS	KXE00	CONDITION					
Range	g	13.3	Factory programmable					
Sensitivity ¹	mV/g	150	Factory programmable					
Offset vs. Temp.	mV	±110	Over temp range					
	°C	-40 to 125 ²						
Sensitivity Error	%	±2.0 typical (±3.0 max)	Over temp range					
Span	mV	±2000						
Noise Density	mg/\sqrt{Hz}	120 typical (200 max)	DC100Hz					
Bandwidth ³	Hz	500 standard	-3dB					
		250, 1000 (preset)	-308					
Non-Linearity	% of FS	± 0.4 typical (± 1.0 max)						
Ratiometric Error	%	±1.7 typical (±2.0 max)						
Cross-Axis Sensitivity	%	±2.0 typical (±3.0 max)						
	V	5.0 ± 0.25						
Power Supply	V	-0.3 (min) 7.0 (max)	Absolute min/max					
	mA	3.5 typical (5.0 max)	Current draw @ 5V					

ENVIRONMENTAL SPECIFICATIONS									
PARAMETERS	UNITS	KXE00	CONDITION						
Operating Temperature	°C	-40 to 125	Powered						
Storage Temperature	°C	-55 to 150	Unpowered						
Mechanical Shock	g	5000	Powered or unpowered, 0.5msec haversine						
ESD	V	3000	Human body model						

Notes

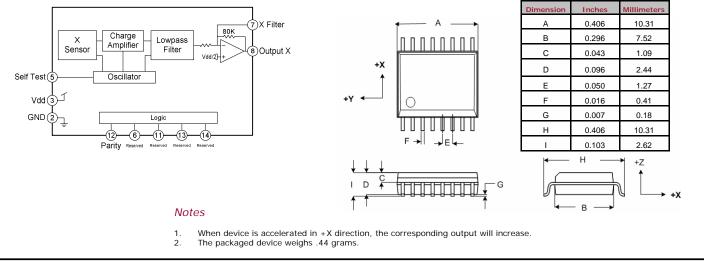
¹ Custom sensitivities from 80mV/g through 200mV/g available.

² Temperature range for specified offset.

³ The internal filter can be bypassed. Lower bandwidth can be achieved by using the external C₂ (see application note on page 3).

FUNCTIONAL DIAGRAM

16-PIN SOIC OVERMOLDED PACKAGE

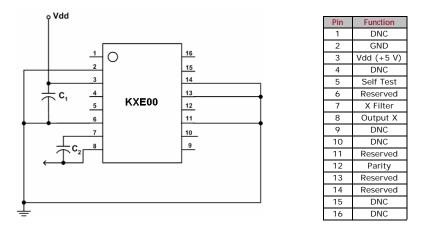




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KXE00 Series

APPLICATION SCHEMATIC & PIN FUNCTION TABLE



Definitions

X FilterAn external capacitor, C2, tied across pins #7 and #8, is used to set the -3dB filter point for the sensor output.DNCDo not connect.

Parity Checks EEPROM for parity error.

Reserved For factory use; recommend grounding.

Self-Test The output of a properly functioning part will increase by at least 1.8V when 5V is applied to the self-test pin (#5).

Application Design Equations

The bandwidth, f_{BW_1} can be adjusted with a capacitor, C_2 , across pins #7 and #8. The response is single pole. Given a desired bandwidth, f_{BW_1} , the filter capacitor, C_2 , is determined by:

$$C_2 = \frac{1.99 \times 10^{-6}}{f_{RW}}$$

Notes

1. Recommend using 0.1 μF for decoupling capacitor $C_1.$

2. An evaluation board is available upon request.

ORDERING GUIDE

Product	Axis of Sensitivity	Range	Sensitivity (mV/g)	Offset (V)	Operating Voltage (V)	Temperature	Package
KXE00-1000	х	13.3g	150	2.5	5	-40 to +125 °C	16-pin SOIC Overmolded

